

# Chez Pierre

Presents ...

Monday, May 5th, 2025

12:00 pm -1:00 pm

Duboc Room – 4-331



## Chez Pierre Seminar

Hadar Steinberg, Hebrew University

### “Universality of Upper Critical Field in the TMD Superconductor Family”.

In transition metal dichalcogenides (TMDs) such as  $H\text{-NbSe}_2$  and  $H\text{-TaS}_2$ , superconducting properties are retained down to a single layer, making these materials useful platforms for studying thickness-dependent effects. Specifically,  $\text{NbSe}_2$  exhibits a reduction in its  $T_C$  from 7.2K in the bulk to approximately 3K in the single-layer limit. In  $\text{TaS}_2$ , conversely,  $T_C$  increases from 0.8K in the bulk to approximately 3K in the single layer limit. This contradicting behavior, which long puzzled researchers, could be related to a thickness-dependent suppression of superconductivity by the competing charge density wave (CDW) phase.

I will present measurements of device-based high-resolution tunneling spectra in  $\text{TaS}_2$ , where we track the gap structure from the bulk all the way to a single layer. Our devices allow for simultaneous evaluation of the gap  $\Delta$ ,  $T_C$ , and the upper critical field  $H_{C2}$ . Although  $\text{TaS}_2$  is considered as a dirty superconductor, we find that  $H_{C2}$  is proportional to  $\Delta^2$ , a relation expected for clean superconductors. Even more curiously, we find that the same ratio between  $H_{C2}$  and  $\Delta^2$  holds for other TMDs:  $\text{NbSe}_2$  of all thicknesses, and  $\text{NbS}_2$  and  $\text{TaSe}_2$ , covering 4 orders of magnitude in  $H_{C2}$  and covering both clean and dirty limits.